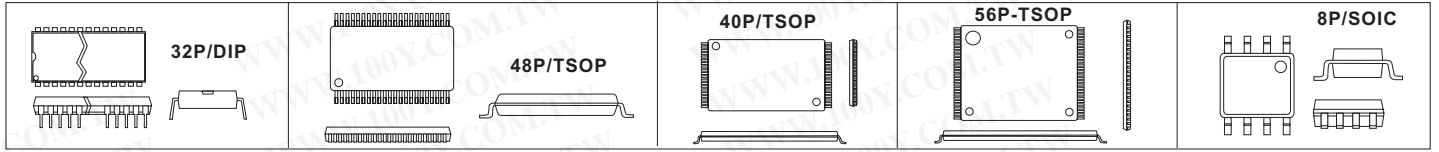




快闪式记忆体

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
18894	E28F016SA-70	INTEL	Word-wide FlashFile memory	56P-TSOP	16M	2M*8/1M*16	70ns	5V
12872	E28F016XD-85	INTEL	16-Mbit (1 Mbit x 16) DRAM-interface flash memory	56P-TSOP	16M	1M*16	85ns	5V
18895	E28F128J3A-150	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	56P/TSOP	128M	512K*8/256K*16	60ns	3V
12579	E28F200BV-B60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	56P/TSOP	2M	256K*8/ 128K*16	60ns	5V
12582	E28F200BV-T60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family.	56P/TSOP	2M	256K*8/128K*16	60ns	5V
12581	E28F200CV-B60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage Boot Block Flash Memory Family	48P/TSOP	2M	256K*8	60ns	5V
12571	E28F200CV-T60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	48P/TSOP	2M	256K*8/128K*16	60ns	5V
18896	E28F320J3A-110	INTEL	32 Megabit Intel StrataFlashR Memory	56P/TSOP	32M	340*161	110ns	5V
12720	E28F400B5B60	INTEL	Smart 5 boot block flash memory 4 Mbit	48P/TSOP	4M	512K*8/256K*16	60ns	5V
12871	E28F400B5B80	INTEL	Smart 5 boot block flash memory 4 Mbit.	48P/TSOP	4M	512K*8	80ns	5V
12819	E28F400B5T60	INTEL	Smart 5 boot block flash memory	56P/TSOP	4M	512K*8/256K*16	60ns	5V
12820	E28F400B5T80	INTEL	Smart 5 boot block flash memory 4 Mbit	56P/TSOP	4M	512K*8/256K*16	80ns	5V
12907	E28F400BV-T60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family.	56P/TSOP	4M	512K*8/256K*16	60ns	5V
12908	E28F400CV-B60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	48P/TSOP	4M	512K*8/256K*16	60ns	5V
12910	E28F400CV-T60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	48P/TSOP	4M	512K*8/256K*16	60ns	5V
42110	E28F640J3A-120	INTEL	FLASH	56P/TSOP	64M		120ns	3V
18897	E28F800CVT-70	INTEL	FLASH	48P/TSOP	8M	512*16	70ns	5V
18898	F28F010C-90	INTEL	FLASH MEMORY	32P/TSOP	1M	128K*8	90ns	5V
18899	GT28F800B3-B90	INTEL	FLASH	40P/TSOP	8M	1024*8	90ns	3V
41480	HY27SF081G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - USOP1	12 x 17 mm.	300us	2ms	1.70 - 1.95 Volt
41479	HY27UF081G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	300us	2ms	2.7V - 3.6 Volt
41482	HY27UF082G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
44351	HY27UF084G2M-TPCB	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41490	HY27UF084G2M-TPCB	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41485	HY27UF162G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41456	HY27US08121A-TP	HYNIX	HIGH DENSITY NAND Flash MEMORIES	48-Pin TSOP1	12 x 20 x 1.2 mm		2ms	2.7 to 3.6V
41465	HY27US08561A	HYNIX	a 32Mx8bit with spare 8Mbit capacity	48-Pin TSOP1		x8		2.7v-3.6v
41437	HY27US08561M	HYNIX	256Mbit (32Mx8bit / 16Mx16bit) NAND Flash Memory	48P-WSOP1	12*17*0.7MM			1.8V-3.3V
22624	IS28F010-45PL	ISSI	131,072 x 8 CMOS FLASH MEMORY	32P/PLCC			45ns	-0.2-7V
15531	IS28F010A-45W	ISSI	"ISSI" FLASH memory	32P/DIP	1Mb	128K*8	45ns	5V
1460	JS28F160C3BD-70	INTEL	Flash RAM(Pb Free)	TSOP	160M			
1459	JS28F160C3TD70	INTEL	Flash RAM(Pb Free)	TSOP	160M			
1452	JS28F320C3BD-70	INTEL	Flash RAM(Pb Free)	TSOP	320M			
40950	K9F1G08U0A-PIB0	SAMSUNG	128M x 8 Bit NAND Flash Memory	48-pin TSOP1	2K-Byte	X8	30ns	2.7 ~ 3.6V
16897	K9F6408UOC-TCB0	SAMSUNG	Flash	44P/TSOP		8M*8	50ns	2.7V
18938	KM29N040T	SAMSUNG	FLASH	TSOP	4M			
18939	LH28F008SAT-85	SHARP	FLASH MEMORY	40P/TSOP	8M	1MB*8	85ns	5V
18940	LH28F008SCHT-TL12	SHARP	8M(X8)FLASH MEMORY	40P/TSOP	8M	8M*8	120ns	5V
18941	LH28F160S3T-L10	SHARP	16M(x8/x16)FLASH MEMORY	56P/TSOP	16M	2M*8	100ns	2.7V
18942	LH28F160S5HNS-L70	SHARP	16M(x8/x16)FLASH MEMORY	56P/SSOP	16M	2M*8	70ns	2.7V
18944	LH28F160S5TL-10A	SHARP	16 M-bit (2 MB x 8/1 MB x 16) Smart 5 Flash Memories (Fast Programming)	56P/TSOP	16M	2M*8 or 1M*16	100ns	5V
18945	LH28F800BVHE-BTL90	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY	48P/TSOP	8M	1M*8 or 512K*16	90ns	2.7V
18946	LH28F800SUT-10	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY		8M		100ns	
23371	M25P10-AVMN6	ST(SGS)	Low Voltage, Serial Flash Memory With 40 MHz SPI Bus Interface	8P/SOIC	1 Mbit	128*8		2.7-3.6V
42758	M25P20VMN6	ST(SGS)	2 Mbit, low voltage, Serial Flash memory with 50MHz SPI bus interface	SO-8	2M	256K*8-Series	50MHz	2.7 to 3.6V
26835	M25P40-VMN6	ST(SGS)	Low Voltage, Serial Flash Memory With 25 MHz SPI Bus Interface	8P/SO	4M	512K*8-Series	40MHz	2.7-3.6V



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